# FAIRCHILD

SEMICONDUCTOR®

# FDP5500\_F085

## **N-Channel UltraFET Power MOSFET**

## 55V, 80A, 7m $\Omega$

### Features

- Typ  $r_{DS(on)}$  = 5.1m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 80A
- Typ Q<sub>g(10)</sub> = 114nC at V<sub>GS</sub> = 10V
- Simulation Models
   -Temperature Compensated PSPICE and SABER<sup>TM</sup> Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Qualified to AEC Q101
- RoHS Compliant

## Applications

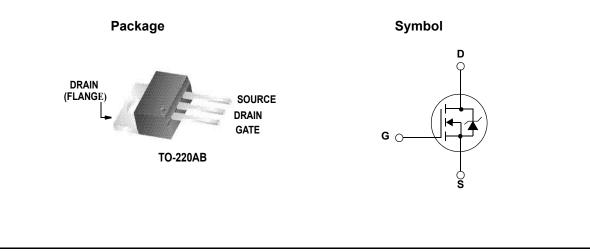
- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems



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FDP5500\_F085 N-Channel UltraFET Power MOSFET





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Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage	(Note 1)	55	V
V <sub>DGR</sub>	Drain to Gate Voltage ( $R_{GS}$ = 20k $\Omega$ )	(Note 1)	55	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
	Drain Current Continuous (T <sub>C</sub> < 135 <sup>o</sup> C, V <sub>GS</sub> = 10V)		80	Α
D	Pulsed		See Figure 4	A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	860	mJ
П	Power Dissipation		375	W
P <sub>D</sub>	Derate above 25°C		2.5	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	
ΤL	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T <sub>pkg</sub>	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.4	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient TO-220AB, 1in <sup>2</sup> copper pad area	62	°C/W

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP5500	FDP5500_F085	TO-220AB	Tube	N/A	50 units

## **Electrical Characteristics** $T_{C}$ = 25°C unless otherwise noted

Sy	mbol	Parameter	Test Conditions	Min	Тур	Max	Units

#### **Off Characteristics**

<b>B<sub>VDSS</sub></b>	Drain to Source Breakdown Voltage	$I_{\rm D}$ = 250 $\mu$ A, V <sub>GS</sub> = 0'	V	55	-	-	V
	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0	IV .	-	-	1	
DSS	Zero Gale voltage Drain Current	V <sub>DS</sub> = 45V	T <sub>C</sub> = 150 <sup>o</sup> C	-	-	250	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = ±20V		-	-	±100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.8	4	V
r <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V	-	5.1	7	mΩ

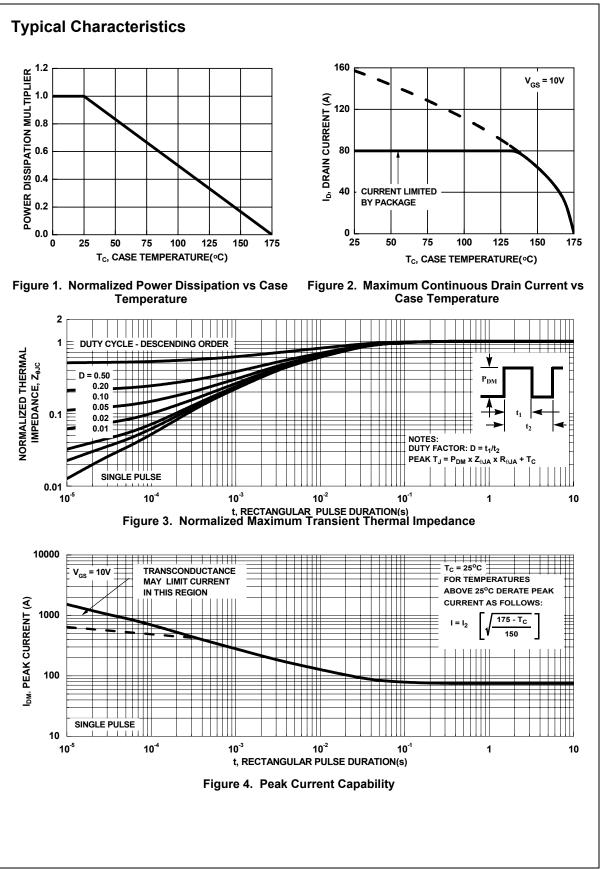
### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance		0)/	-	3565	-	pF
C <sub>oss</sub>	Output Capacitance	───V <sub>DS</sub> = 25V, V <sub>GS</sub> = f = 1MHz	0ν,	-	1310	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	395	-	pF
Q <sub>g(TOT)</sub>	Total Gate Charge at 20V	V <sub>GS</sub> = 0 to 20V		-	207	269	nC
Q <sub>g(10)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	$V_{DD} = 30V$	-	114	148	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	I <sub>D</sub> = 80A R <sub>1</sub> = 0.4Ω	-	6.6	8.6	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		$I_{a} = 1.0 \text{mA}$	-	17.2	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge		g	-	52	-	nC

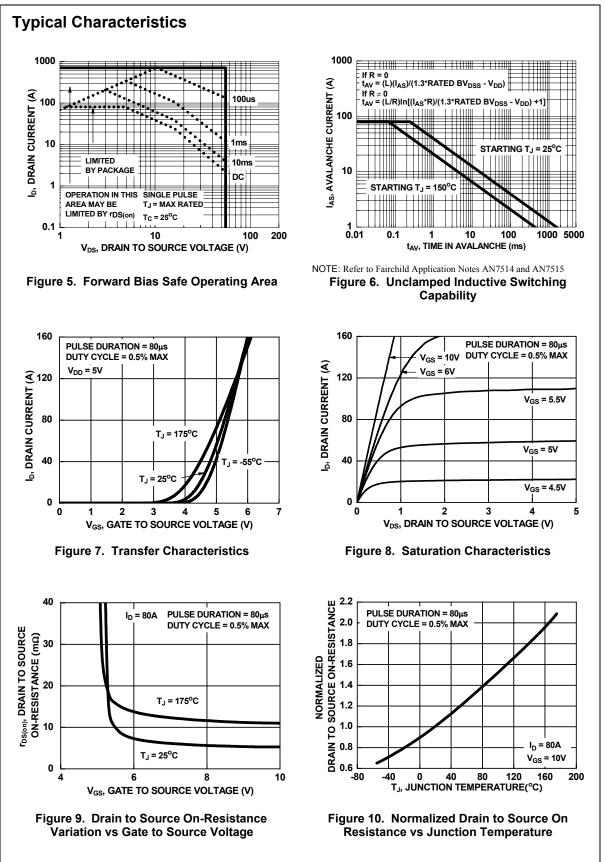
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ning Characteristics					
t <sub>on</sub>	Turn-On Time		-	-	75	ns
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = 30V, I_D = 80A,$ 	-	12	-	ns
t <sub>r</sub>	Rise Time		-	34	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	37	-	ns
t <sub>f</sub>	Fall Time		-	23	-	ns
t <sub>off</sub> Drain-S	Turn-Off Time ource Diode Characteristics		-	-	96	ns
		I <sub>SD</sub> = 80A	-	- 0.9	96	ns V
Drain-S	ource Diode Characteristics					

FDP5500\_F085 Rev. A

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

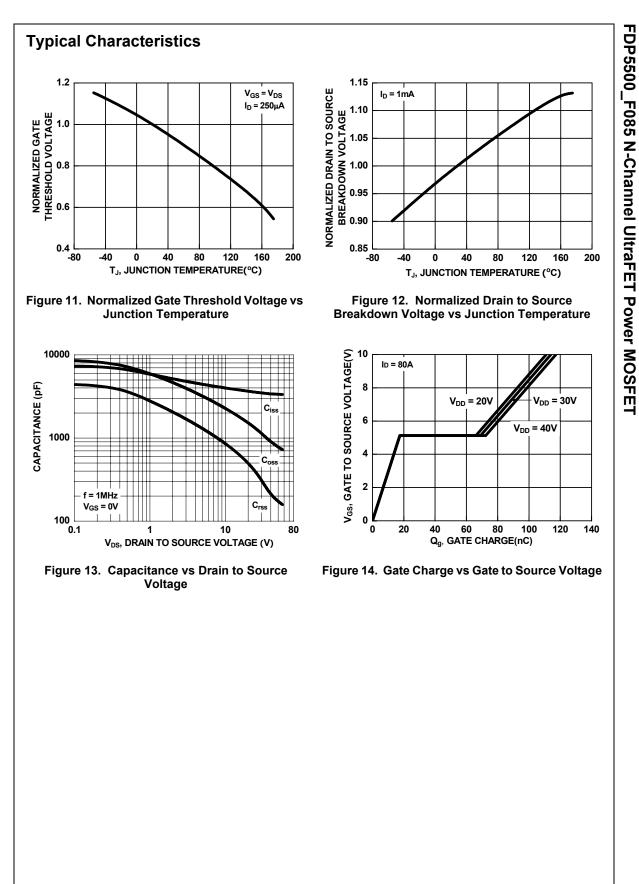


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TL™	G <i>ma</i> x™	Quiet Series™	TinyBuck™
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